



## 20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 5.8A

#### **Features**

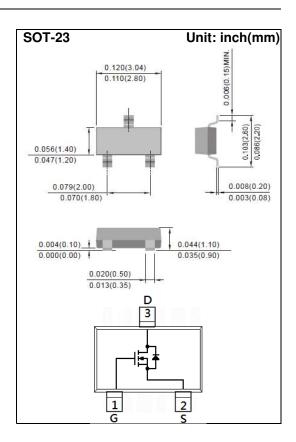
- RDS(ON), VGS@4.5V, ID@5.8A<27mΩ
- RDS(ON) , VGS@2.5V, ID@3.2A< $40m\Omega$
- RDS(ON) , VGS@1.8V, ID@1.6A<80m $\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc...
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAME   | SYMBOL               | LIMIT                            | UNITS       |       |
|--|----------------------|----------------------------------|-------------|-------|
| Drain-Source Voltage   |                      | V <sub>DS</sub>                  | 20          | V     |
| Gate-Source Voltage  |                      | V <sub>GS</sub>                  | <u>+</u> 12 | V     |
| Continuous Drain Current   |                      | ID                               | 5.8         | Α     |
| Pulsed Drain Current   |                      | I <sub>DM</sub>                  | 23.2        | Α     |
| Power Dissipation  | T <sub>a</sub> =25°C | Б                                | 1.25        | W     |
|  | Derate above 25°C    | P <sub>D</sub>                   | 10          | mW/°C |
| Operating Junction and Storage Temperature Range                     |                      | T <sub>J</sub> ,T <sub>STG</sub> | -55~150     | °C    |
| Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup> |                      | R <sub>θJA</sub>                 | 100         | °C/W  |





## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER                                    | SYMBOL              | TEST CONDITION   | MIN. | TYP.        | MAX.         | UNITS |
|--|---------------------|--|------|-------------|--------------|-------|
| Static                                       |                     |  |      |             |              |       |
| Drain-Source Breakdown Voltage               | BV <sub>DSS</sub>   | $V_{GS}=0V$ , $I_D=250uA$  | 20   | -           | -            | V     |
| Gate Threshold Voltage                       | $V_{GS(th)}$        | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA                       | 0.5  | 0.77        | 1.2          | V     |
| Drain-Source On-State Resistance             | R <sub>DS(on)</sub> | V <sub>GS</sub> =4.5V, I <sub>D</sub> =5.8A                                    | -    | 23          | 27           | mΩ    |
|  |                     | $V_{GS}=2.5V$ , $I_{D}=3.2A$   | -    | 32          | 40           |       |
|  |                     | V <sub>GS</sub> =1.8V, I <sub>D</sub> =1.6A                                    | -    | 61          | 80           |       |
| Zero Gate Voltage Drain Current              | I <sub>DSS</sub>    | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V                                      | -    | 0.01        | 1            | uA    |
| Gate-Source Leakage Current                  | I <sub>GSS</sub>    | V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V                            | -    | <u>+</u> 10 | <u>+</u> 100 | nA    |
| Dynamic                                      |                     |  |      |             |              |       |
| Total Gate Charge                            | $Q_g$               | $V_{DS}$ =10V, $I_{D}$ =5.8A, $V_{GS}$ =4.5V <sup>(Note 1,2)</sup>             | -    | 6.7         | -            | nC    |
| Gate-Source Charge                           | $Q_{gs}$            |  | -    | 1.2         | -            |       |
| Gate-Drain Charge                            | $Q_{gd}$            |  | -    | 2           | -            |       |
| Input Capacitance                            | Ciss                | V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,                                     | -    | 513         | -            | pF    |
| Output Capacitance                           | Coss                |  | -    | 75          | -            |       |
| Reverse Transfer Capacitance                 | Crss                | f=1.0MHZ   | -    | 59          | -            |       |
| Switching                                    |                     |  |      |             |              |       |
| Turn-On Delay Time                           | td <sub>(on)</sub>  | $V_{DD}$ =10V, $I_{D}$ =5.8A, $V_{GS}$ =4.5V, $R_{G}$ =6 $\Omega^{(Note 1,2)}$ | -    | 6           | -            | ns    |
| Turn-On Rise Time                            | tr                  |  | -    | 56          | -            |       |
| Turn-Off Delay Time                          | td <sub>(off)</sub> |  | -    | 23          | -            |       |
| Turn-Off Fall Time                           | tf                  | ng=012(1000 1)=/   | -    | 13          | -            |       |
| Drain-Source Diode                           |                     |  |      |             |              |       |
| Maximum Continuous Drain-Source              | Is                  |  | -    | -           | 1.5          | Α     |
| Diode Forward Current  Diode Forward Voltage | V <sub>SD</sub>     | I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V                                      | -    | 0.71        | 1.2          | V     |

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





## TYPICAL CHARACTERISTIC CURVES

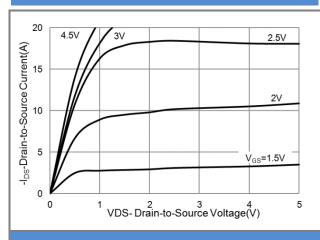


Fig.1 On-Region Characteristics

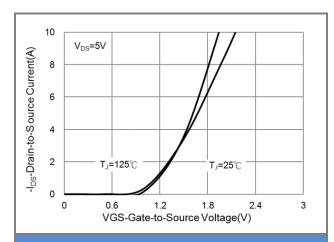


Fig.2 Transfer Characteristics

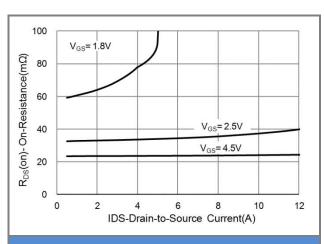


Fig.3 On-Resistance vs. Drain Current

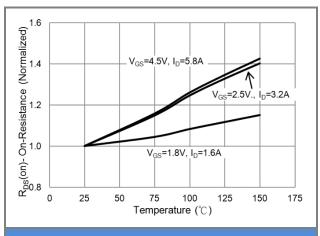
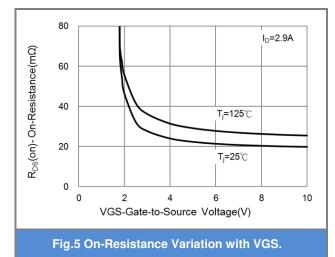
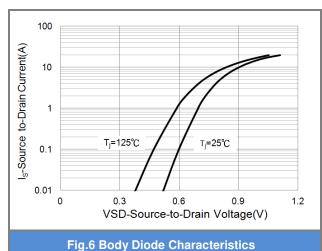


Fig.4 On-Resistance vs. Junction temperature









#### **TYPICAL CHARACTERISTIC CURVES**

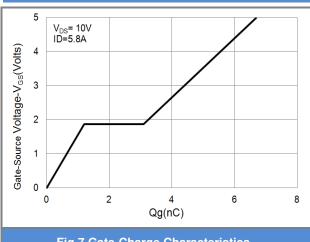


Fig.7 Gate-Charge Characteristics

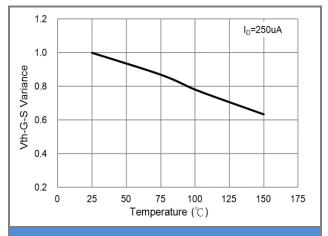


Fig.8 Threshold Voltage Variation with Temperature.

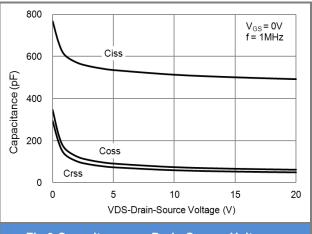


Fig.9 Capacitance vs. Drain-Source Voltage.

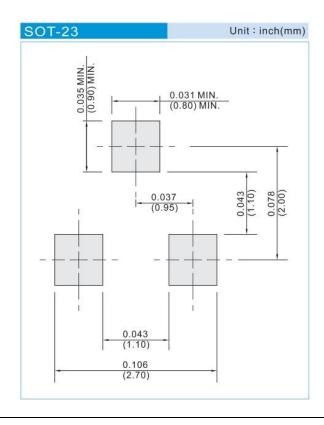




## PART NO. PACKING CODE VERSION

| Part No. Packing Code | Package Type | Packing Type       | Marking | Version                        |
|-----------------------|--------------|--------------------|---------|--------------------------------|
| PJA3416_R1_00001      | SOT-23       | 3K pcs / 7" reel   | A16     | Halogen free<br>RoHS compliant |
| PJA3416_R2_00001      | SOT-23       | 12K pcs / 13" reel | A16     | Halogen free<br>RoHS compliant |

### **MOUNTING PAD LAYOUT**







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